## Display Elektronik GmbH

# DATA SHEET

## STANDARD OLED/PLED

## **DEP 096032B-W**

**Product Specification** 

Version: 02

25.05.2009

### **History of Version**

Version	Contents	Date	Note
01	NEW VERSION	2009/03/02	SPEC.
02	CHANGE PIN LAYOUT	2009/05/25	МН

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### 1. Numbering System

### 2. General Specification

#### (1) Mechanical Dimension

Item	Standard Value	Unit
Number of dots	96x32	dots
Module dimension (L*W*H)	28.5*11.5*1.41(MAX)	mm
Active area	19.18*6.38	mm
Dot size	0.18(W)×0.18(H)	mm
Dot pitch	0.20(W)×0.20 (H)	mm
Color	White	

#### (2) Controller IC: SSD1307 Controller

#### (3) Temperature Range

Operating	-40 ~ +70
Storage	-40 ~ +85

### 3. Absolute Maximum Ratings

Item	Symbol	Min	Тур	Max	Unit
Operating Temperature	ТОР	-40	-	+70	
Storage Temperature	TST	-40	-	+85	
Humidity		-	-	85	%
Supply Voltage For Logic	VDD	-0.3	-	4	V
Supply Voltage For Panel	Vcc	7	-	16	V
Operating lifetime			30,000(*)		Hrs

<sup>\*:100</sup>cd/m<sup>2</sup> light on

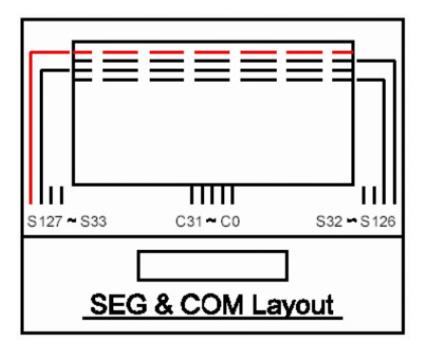
### 4. Electrical Characteristics

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Supply Voltage For Logic	$V_{\mathrm{DD}}$ - $V_{\mathrm{SS}}$	-	1.65	2.8	3.3	V
Supply Voltage For Panel	Vcc-V <sub>SS</sub>	-	11.5	12	12.5	V
Input High Vol	V <sub>IH</sub>	-	$0.8V_{\mathrm{DD}}$	-	-	V
Input Low Vol	$V_{\rm IL}$	-	-	-	$0.2V_{\mathrm{DD}}$	V
Output High Vol	$V_{OH}$	-	$0.9V_{DD}$	-	-	V
Output Low Vol.	$V_{OL}$	-	-	-	$0.1V_{DD}$	V
Supply Current For Logic	$I_{DD}$	All pixels on	-	5	6	mA

### **5. Optical Characteristics**

Item	Min.	Тур.	Max.	Unit
View Angle	160	-	-	deg
Dark Room contrast	2000:1	-	-	-
Response Time	-	10	-	us

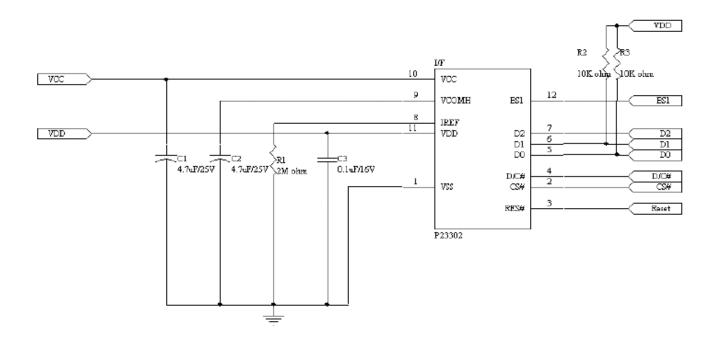
### 6. Panel Layout Diagram



### 7. Interface Pin Function

Pin No.	Symbol	Description
1	VSS	This is a ground pin.
2	CS	This pin is the chip select input.
3	RES	Hardware reset signal
4	D/C	In 4-wire Serial mode, this is Data/Command control pin. In I <sub>2</sub> C mode, this pin acts as SA0 for slave address selection.
5	D0	4-wire SPI: SCLK I2C: SCL
6	D1	4-wire SPI: SDIN I2C: SDAIN
7	D2	4-wire SPI: NC I <sub>2</sub> C: SDAOUT
8	IREF	The current reference input pin, this pin should be connected to ground through a resistor
9	VCOMH	The COM voltage reference pin, this pin should be connected to ground through a capacitor.
10	VCC	Positive OLED high voltage power supply
11	VDD	Power supply for logic circuit
12	BS1	MCU Bus Interface Pin Selection 0: 4-wire Serial Interface 1: I2C Interface

### 8. Power Supply For LCD Module



### Component:

C1 · C2 : 4.7uF/16V(0805)

C3: 0.1uF/16V(0603)

R1: 2M ohm 1%(0603)

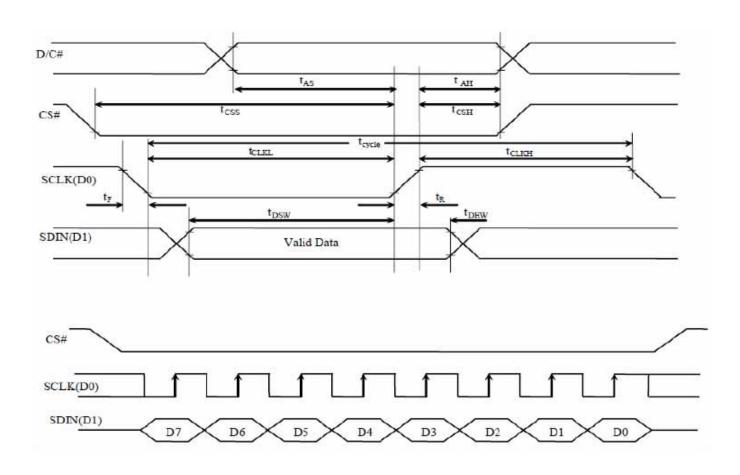
R2 · R3 : 10K ohm (0603)

This circuit is for I<sup>2</sup>C Interface

### 9. Timing Characteristics

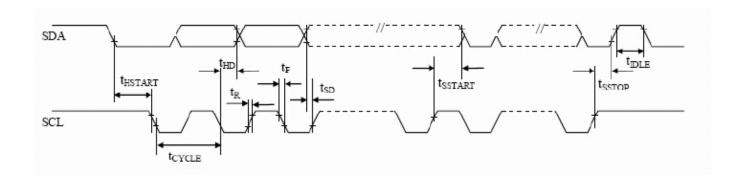
#### 9-1.SPI Interface

Symbol	Parameter	Min	Тур	Max	Unit
t <sub>cycle</sub>	Clock Cycle Time	100	-	-	ns
t <sub>AS</sub>	Address Setup Time	15	-	-	ns
t <sub>AH</sub>	Address Hold Time	15	-	-	ns
t <sub>CSS</sub>	Chip Select Setup Time	20	-	-	ns
t <sub>CSH</sub>	Chip Select Hold Time	10	-	-	ns
t <sub>DSW</sub>	Write Data Setup Time	15	-	-	ns
t <sub>DHW</sub>	Write Data Hold Time	15	-	-	ns
t <sub>CLKL</sub>	Clock Low Time	20	-	-	ns
t <sub>CLKH</sub>	Clock High Time	20	-	-	ns
t <sub>R</sub>	Rise Time	-	-	40	ns
t <sub>F</sub>	Fall Time	-	-	40	ns
			_		



#### 9-2.I2C Interface

Symbol	Parameter	Min	Тур	Max	Unit
t <sub>cycle</sub>	Clock Cycle Time	2.5	-	-	us
tHSTART	Start condition Hold Time	0.6	-	-	us
t <sub>HD</sub>	Data Hold Time (for "SDA <sub>OUT</sub> " pin)	0	-	-	ns
	Data Hold Time (for "SDA <sub>IN</sub> " pin)	300	-	-	ns
t <sub>SD</sub>	Data Setup Time	100	-	-	ns
t <sub>SSTART</sub>	Start condition Setup Time (Only relevant for a repeated Start condition)	0.6	-	-	us
tSSTOP	Stop condition Setup Time	0.6	-	-	us
t <sub>R</sub>	Rise Time for data and clock pin	-	-	300	ns
t <sub>F</sub>	Fall Time for data and clock pin	-	-	300	ns
t <sub>IDLE</sub>	Idle Time before a new transmission can start	1.3	-	-	us

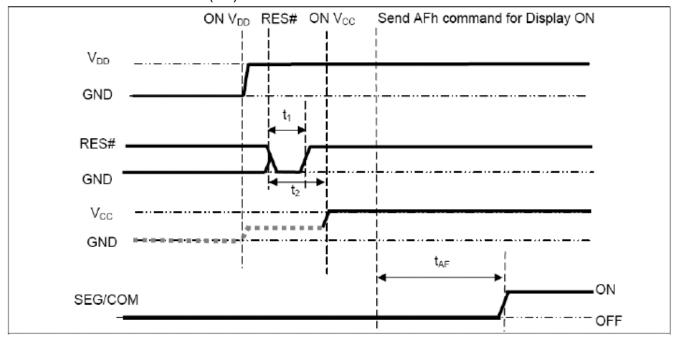


#### 10. Power ON / OFF Sequence & Application Circuit

#### 10.1 POWER ON / OFF SEQUENCE

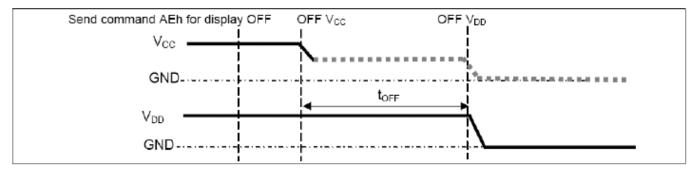
#### **Power ON sequence:**

- 1. Power ON VDD.
- 2. After VDD become stable, set RES# pin LOW (logic low) for at least 3us(t1) and then HIGH (logic high).
- 3. After set RES# pin LOW (logic low ), wait for at least 3us(t2). Then Power ON Vcc.(1)
- 4. After Vcc become stable, send command AFh for display ON. SEG/COM will be ON after 100ms(taf).



#### **Power OFF sequence:**

- 1. Send command AEh for display OFF.
- 2. Wait until panel discharges completely.
- 3. Power OFF Vcc. (1), (2)
- 4. Wait for toff. Power OFF VDD. (where Minimum toff=80ms, Typical toff=100ms)



#### Note:

- (1) Since an ESD protection circuit is connected between VDD and VCC, VCC becomes lower than VDD whenever VDD is ON and VCC is OFF as shown in the dotted line of VCC in above figures.
- (2) VCC should be disabled when it is OFF.

#### 11. GRAPHIC DISPLAY DATA RAM ADDRESS MAP

The GDDRAM is a bit mapped static RAM holding the bit pattern to be displayed.

The size of the RAM is 128 x 39 bits and the RAM is divided into five pages, from PAGE0 to PAGE4, which are used for monochrome 128x39 dot matrix display, as shown in below figures.

When one data byte is written into GDDRAM, all the rows image data of the same page of the current column are filled (i.e. the whole column (8 bits) pointed by the column address pointer is filled.). Data bit D0 is written into the top row, while data bit D7 is written into bottom row. For PAGE4, bit D7 is treated as don't care bit.

For mechanical flexibility, re-mapping on both Segment and Common outputs can be selected by software. For vertical shifting of the display, an internal register storing the display start line can be set to control the portion of the RAM data to be mapped to the display (command D3h).

					GD:	DRAM pages structur	e of	SSD	130	7			
Segmer mapping (co A1h	ommand	SEG127	SEG126	SEG125	SEG124	******	SEG4	SEG3	SEG2	SEG1	SEGO		
Segmer mapping (co A0h [RE:	ommand	SEGO	SEG1	SEG2	SEG3	*******	SEG123	SEG124	SEG125	SEG126	SEG127		
Page Da	ata	COLO	001.1	2002	S)		COL123	OOL124	COL125	OOL126	∞L127	COM Output Scan Direction (command C0h [RESET])	COM Output Scan Direction (command C8h)
D	0.											COM0	COM38
D	2.7.			Q 9								COM1 COM2	COM37 COM36
D				9 7								COM3	COM35
0 0	(20)			-	$\vdash$	******		-		Н		COM4	COM34
D	175									Н		COM5	COM33
D					$\vdash$					Н		COM6	COM32
ă										П		COM7	COM31
D	0		-					-			-	COM8	COM30
D		-								$\Box$		COM9	COM29
D	12.							0 0	$\vdash$	М		COM10	COM28
D										П		COM11	COM27
1 6			- 5			*******	- 5	7		П	-0	COM12	COM26
D			- 7					3				COM13	COM25
D					1				$\vdash$	П		COM14	COM24
D	7				-					П		COM15	COM23
D	0					_				П		COM16	COM22
D	1			4-4		Each box repre	sen	ts o	ne	bit		COM17	COM21
D	0.50		F 78	$\overline{}$		of image data	,5011			Ή	-	COM18	COM20
D						or image data	D 8	64 19		_		COM19	COM19
2 D				Ï		San Design				Н		COM20	COM18
D	5									М		COM21	COM17
D	6		3 3	9 7				8				COM22	COM16
D			F 78			8		8 4			1	COM23	COM15
D	0											COM24	COM14
D			12	ŢŢ								COM25	COM13
D	2									П		COM26	COM12
3 D	777							1 0				COM27	COM11
3 D								1				COM28	COM10
D								Ĵij	П	П		COM29	COM9
D										П		COM30	COM8
D	7		9	1				2				COM31	COM7
D	0		- 1-	ÿ ř	1		- 6	-0 - 7		П	- 6	COM32	COM6
D												COM33	COM5
D	2	)		j j				J i				COM34	COM4
4 D						*****	c					COM35	COM3
D	4		T			0000 OF 1000						COM36	COM2
D	5		- 1-	¢ #			- 0-	-0 - 7			- 0	COM37	COM1
D6	170									П		COM38	COM0
D	7	-	-	_	_	Don't care bit	_	-	_		_		A.

**12. Reliability**Content of Reliability Test

NO.	Items.	Specification	Applicable Standard
1	High temp. (Non-operation)	85°C, 240hrs	
2	High temp. (Operation)	70°C, 120hrs	
3	Low temp. (Operation)	-40°C, 120hrs	
4	High temp. / High. humidity (Operation)	65°C, 90%RH, 120hrs	
5	Thermal shock(Non-operation)	-40°C ~85°C (-40°C /30min; transit /3min; 85°C /30min; transit /3min) 1cycle: 66min, 100 cycles.	
6	Vibration	Frequency: 5~50HZ, 0.5G Scan rate: 1 oct/min Time: 2 hrs/axis Test axis: X, Y, Z	
7	Drop	Height: 120cm Sequence: 1 angle, 3 edges and faces Cycles: 1	
8	ESD (Non-operation)	Air discharge model, ±8kV, 10 times	

### 13. Appendix ( Drawing )

